KM4210

Dual, 0.5mA, Low Cost, +2.7V & +5V, 75MHz Rail-to-Rail Amp

Features

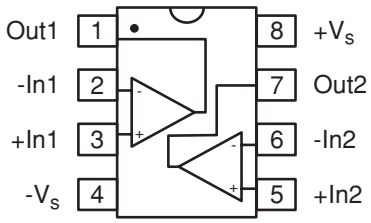
- 505μA supply current
- 75MHz bandwidth
- Power down to I_S = 33μA (KM4120)
- Fully specified at +2.7V and +5V supplies
- Output voltage range: 0.07V to 4.86V; V_S = +5
- Input voltage range: -0.3V to +3.8V; V_S = +5
- 50V/μs slew rate
- ±15mA linear output current
- ±30mA output short circuit current
- 12nV/√Hz input voltage noise
- Directly replaces AD8032 in single supply applications
- Small package options (SOIC-8 and MSOP-8)

Applications

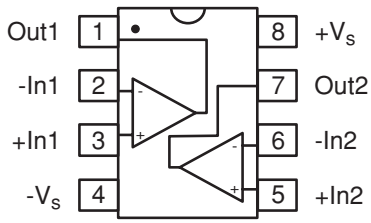
- Portable/battery-powered applications
- A/D buffer
- Active filters
- Signal conditioning
- Portable test instruments

KM4210 Packages

SOIC-8



MSOP-8



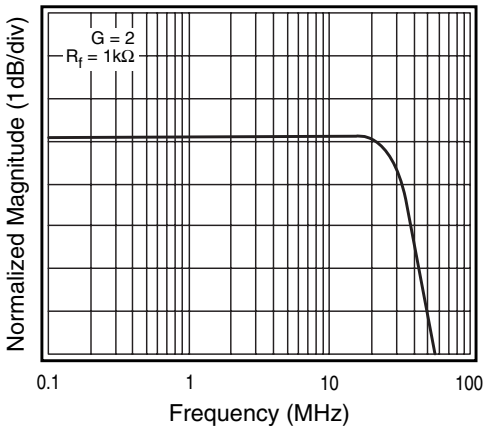
General Description

The KM4210 is a dual, low power, low cost, voltage feedback amplifier. The KM4210 uses only 505μA of supply current per amplifier, and is designed to operate on +2.7V, +5V, or ±2.5V supplies. The input voltage range extends 300mV below the negative rail and 1.2V below the positive rail.

The KM4210 offers high bipolar performance at a low CMOS price. The KM4210 offers superior dynamic performance with a 75MHz small signal bandwidth and 50V/μs slew rate. The combination of low power, high bandwidth, and rail-to-rail performance make the KM4210 well suited for battery-powered communication/computing systems.

The KM4110 (single) and KM4120 (single with disable) are also available.

Non-Inverting Freq. Response V_S = +5V



KM4210 Electrical Characteristics (V_s = +2.7V, G = 2, R_L = 1kΩ to V_s/2, R_f = 1kΩ; unless noted)

Parameters	Conditions	TYP	Min & Max	UNITS	NOTES
Case Temperature		+25°C	+25°C		
Frequency Domain Response					
-3dB bandwidth	G = +1, V_O = 0.05V_{pp}	65		MHz	1
	G = +2, V_O < 0.2V_{pp}	30		MHz	
full power bandwidth	G = +2, V_O = 2V_{pp}	12		MHz	
gain bandwidth product		28		MHz	
Time Domain Response					
rise and fall time	0.2V step	7.5		ns	
settling time to 0.1%	1V step	60		ns	
overshoot	1V step,	4		%	
slew rate	2V step, G = -1	40		V/μs	
Distortion and Noise Response					
2nd harmonic distortion	1V_{pp}, 1MHz	67		dBc	
3rd harmonic distortion	1V_{pp}, 1MHz	72		dBc	
THD	1V_{pp}, 1MHz	65		dB	
input voltage noise	>10kHz	12		nV/√Hz	
crosstalk	100kHz	90		dB	
DC Performance					
input offset voltage		0	±5	mV	2
average drift		10		μV/°C	
input bias current		1.2	±3.5	μA	2
average drift		3.5		nA/°C	
input offset current		30	350	nA	2
power supply rejection ratio	DC	66	60	dB	2
open loop gain		98	65	dB	2
quiescent current per channel		470	600	μA	2
Input Characteristics					
input resistance		9		MΩ	
input capacitance		1.7		pF	
input common mode voltage range		-0.3 to 1.5		V	
common mode rejection ratio	DC, V_{cm} = 0V to V_s - 1.5	98	78	dB	2
Output Characteristics					
output voltage swing	R_L = 10kΩ to V_s/2	0.05 to 2.6		V	
	R_L = 1kΩ to V_s/2	0.09 to 2.53	0.2 to 2.35	V	2
linear output current		±15		mA	
short circuit output current		±25		mA	
power supply operating range		2.7	2.5 to 5.5	V	

Min/max ratings are based on product characterization and simulation. Individual parameters are tested as noted. Outgoing quality levels are determined from tested parameters.

NOTES:

1) For G = +1, R_f = 0.

2) 100% tested at +25°C.

Absolute Maximum Ratings

supply voltage	0 to +6V
maximum junction temperature	+175°C
storage temperature range	-65°C to +150°C
lead temperature (10 sec)	+260°C
operating temperature range (recommended)	-40°C to +85°C
input voltage range	+V_s +0.5V; -V_s -0.5V
internal power dissipation	see power derating curves

Package Thermal Resistance

Package	θ_{JA}
8 lead SOIC	152°C/W
8 lead MSOP	206°C/W

KM4210 Electrical Characteristics (V_s = +5V, G = 2, R_L = 1kΩ to V_s/2, R_f = 1kΩ; unless noted)

PARAMETERS	CONDITIONS	TYP	MIN & MAX	UNITS	NOTES
Case Temperature		+25°C	+25°C		
Frequency Domain Response					
-3dB bandwidth	G = +1, V_O = 0.05V_{pp}	75		MHz	1
	G = +2, V_O < 0.2V_{pp}	35		MHz	
full power bandwidth	G = +2, V_O = 2V_{pp}	15		MHz	
gain bandwidth product		33		MHz	
Time Domain Response					
rise and fall time	0.2V step	6		ns	
settling time to 0.1%	2V step	60		ns	
overshoot	2V step,	3		%	
slew rate	2V step, G = -1	50		V/µs	
Distortion and Noise Response					
2nd harmonic distortion	2V_{pp}, 1MHz	64		dBc	
3rd harmonic distortion	2V_{pp}, 1MHz	62		dBc	
THD	2V_{pp}, 1MHz	60		dB	
input voltage noise	>10kHz	12		nV/√Hz	
crosstalk	100kHz	90		dB	
DC Performance					
input offset voltage		-1		mV	
average drift		10		µV/°C	
input bias current		1.2		µA	
average drift		3.5		nA/°C	
input offset current		30		nA	
power supply rejection ratio	DC	65		dB	
open loop gain		80		dB	
quiescent current per channel		505		µA	
Input Characteristics					
input resistance		9		MΩ	
input capacitance		1.5		pF	
input common mode voltage range		-0.3 to 3.8		V	
common mode rejection ratio	DC, V_{cm} = 0V to V_s - 1.5	92		dB	
Output Characteristics					
output voltage swing	R_L = 10kΩ to V_s/2	0.08 to 4.84		V	
	R_L = 1kΩ to V_s/2	0.13 to 4.73		V	
linear output current		±15		mA	
short circuit output current		±30		mA	
power supply operating range		5	2.5 to 5.5	V	

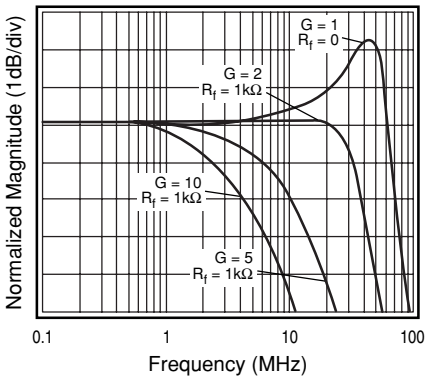
Min/max ratings are based on product characterization and simulation. Individual parameters are tested as noted. Outgoing quality levels are determined from tested parameters.

NOTES:

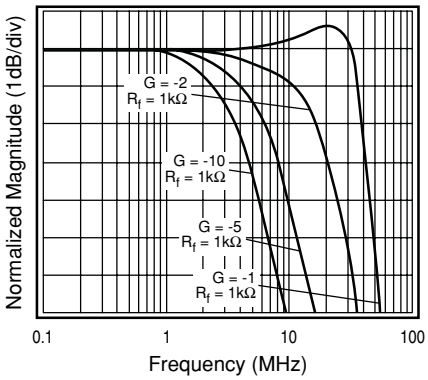
1) For G = +1, R_f = 0.

KM4210 Performance Characteristics (V_S = +5V, G = 2, R_L = 1kΩ to V_S/2, R_f = 1kΩ; unless noted)

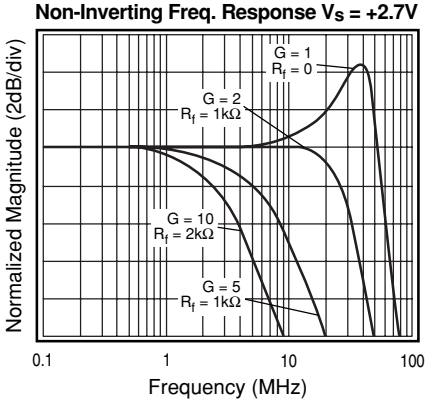
Non-Inverting Freq. Response V_S = +5V



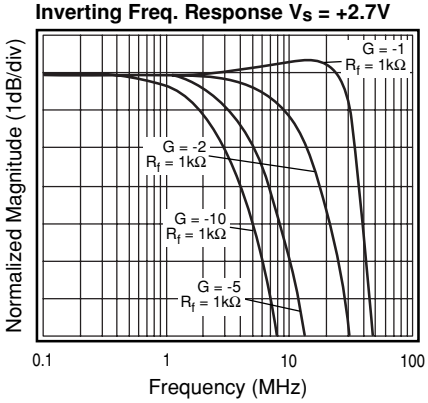
Inverting Freq. Response V_S = +5V



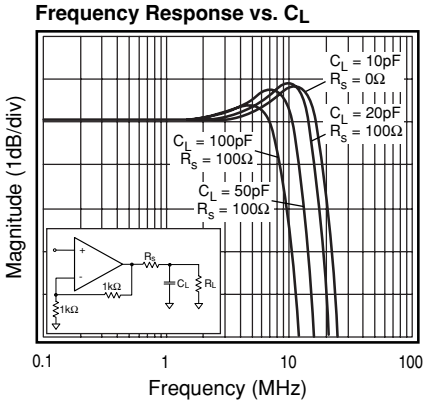
Non-Inverting Freq. Response V_S = +2.7V



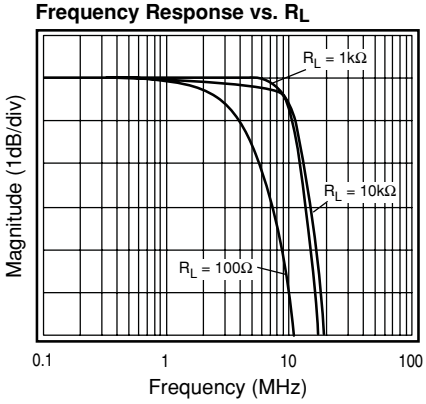
Inverting Freq. Response V_S = +2.7V



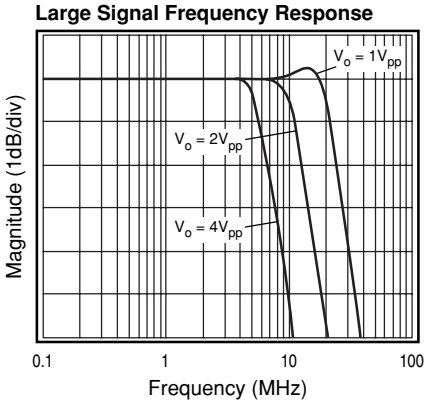
Frequency Response vs. C_L



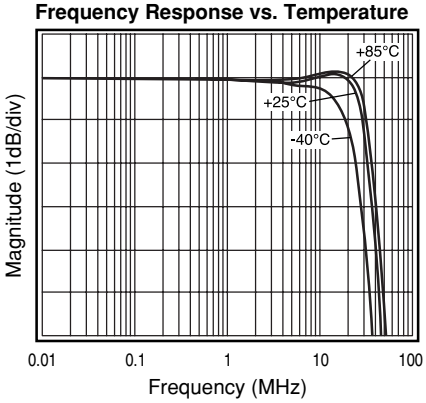
Frequency Response vs. R_L



Large Signal Frequency Response

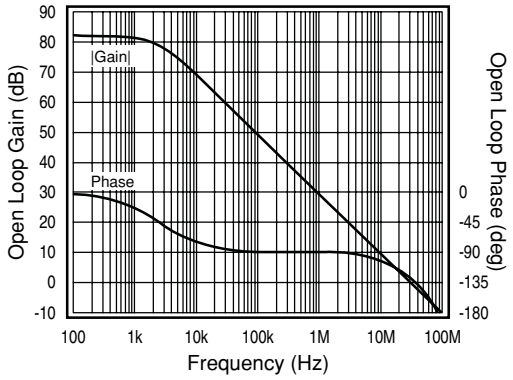


Frequency Response vs. Temperature

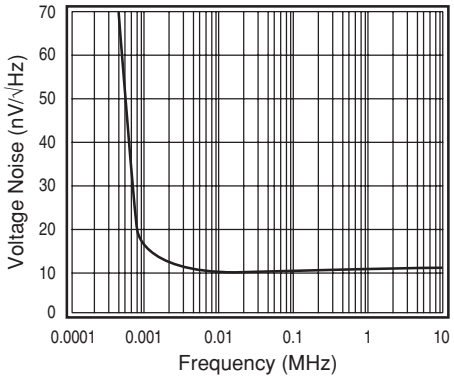


KM4210 Performance Characteristics (V_s = +5V, G = 2, R_L = 1kΩ to V_s/2, R_f = 1kΩ; unless noted)

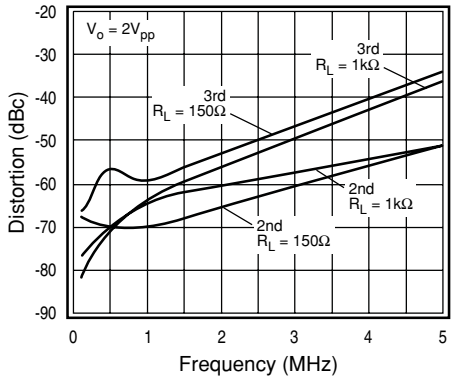
Open Loop Gain & Phase vs. Frequency



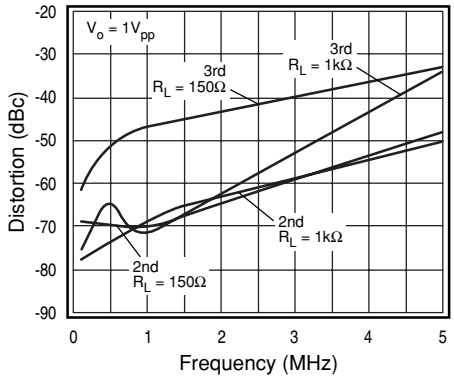
Input Voltage Noise



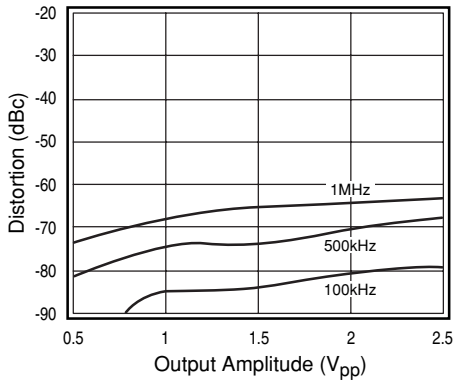
2nd & 3rd Harmonic Distortion; V_S = +5V



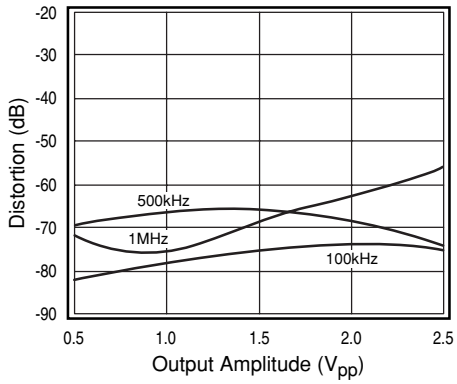
2nd & 3rd Harmonic Distortion; V_S = +2.7V



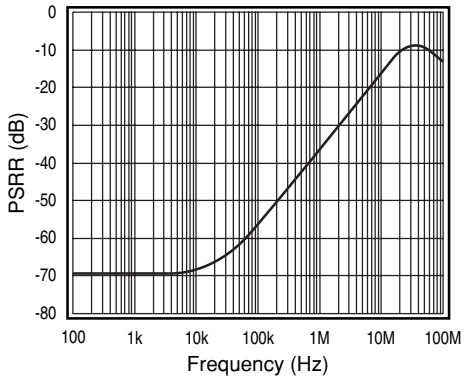
2nd Harmonic Distortion vs. V_O



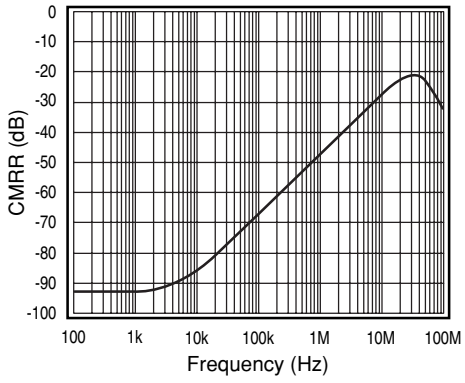
3rd Harmonic Distortion vs. V_O



PSRR

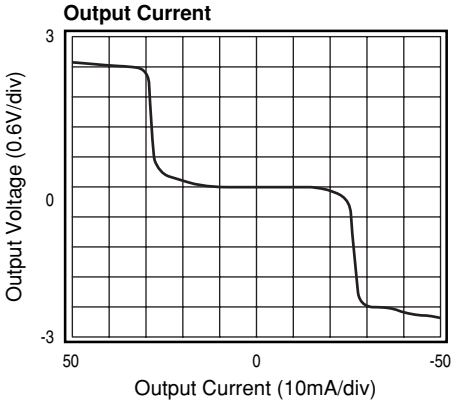


CMRR

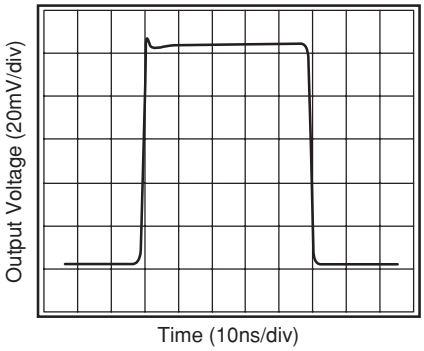


KM4210 Performance Characteristics (V_s = +5V, G = 2, R_L = 1kΩ to V_s/2, R_f = 1kΩ; unless noted)

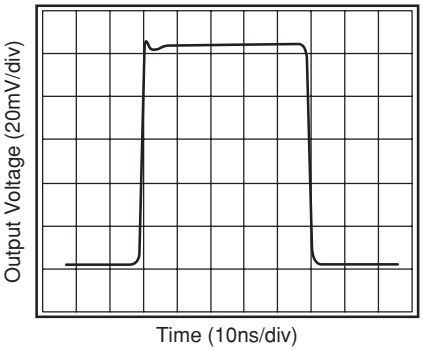
Output Current



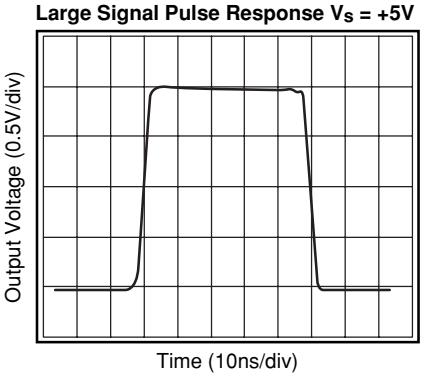
Small Signal Pulse Response V_S = +5V



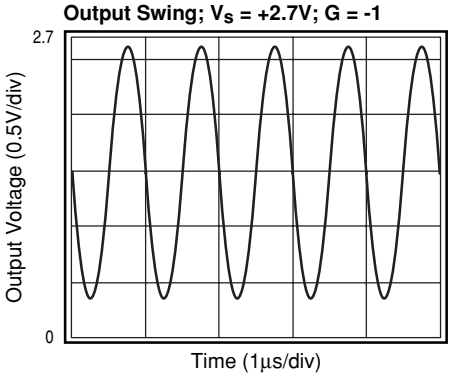
Small Signal Pulse Response V_S = +2.7V



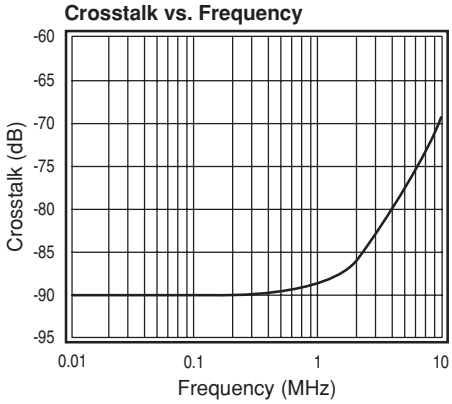
Large Signal Pulse Response V_S = +5V



Output Swing; V_S = +2.7V; G = -1



Crosstalk vs. Frequency



General Description

The KM4110 is a single supply, general purpose, voltage-feedback amplifier fabricated on a complementary bipolar process. The KM4110 offers 75MHz unity gain bandwidth, 50V/μs slew rate, and only 505μA supply current. It features a rail-to-rail output stage and is unity gain stable.

The design utilizes a patent pending topology that provides increased slew rate performance. The common mode input range extends to 300mV below ground and to 1.2V below V_S. Exceeding these values will not cause phase reversal. However, if the input voltage exceeds the rails by more than 0.5V, the input ESD devices will begin to conduct. The output will stay at the rail during this overdrive condition.

The design uses a Darlington output stage. The output stage is short circuit protected and offers "soft" saturation protection that improves recovery time.

The typical circuit schematic is shown in Figure 1.

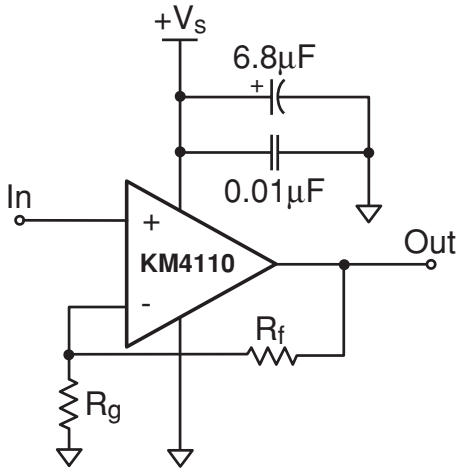


Figure 1: Typical Configuration

For optimum response at a gain of +2, a feedback resistor of 1kΩ is recommended. Figure 2 illustrates the KM4110 frequency response with both 1kΩ and 2kΩ feedback resistors.

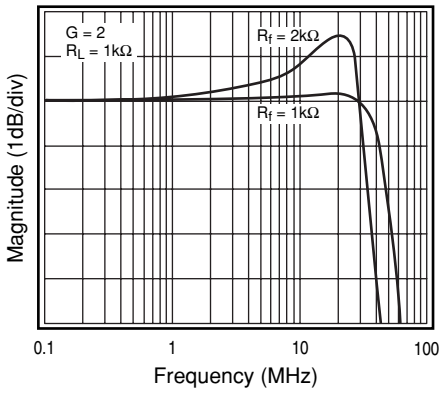


Figure 2: Frequency Response vs. R_f

Power Dissipation

The maximum internal power dissipation allowed is directly related to the maximum junction temperature. If the maximum junction temperature exceeds 150°C, some reliability degradation will occur. If the maximum junction temperature exceeds 175°C for an extended time, device failure may occur.

The KM4110 is short circuit protected. However, this may not guarantee that the maximum junction temperature (+150°C) is not exceeded under all conditions. Follow the maximum power derating curves shown in Figure 3 to ensure proper operation.

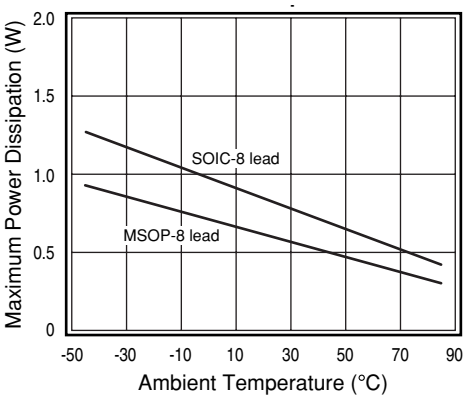


Figure 3: Power Derating Curves

Overdrive Recovery

For an amplifier, an overdrive condition occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the ranges are exceeded. The KM4110 will typically recover in less than 20ns from an overdrive condition. Figure 4 shows the KM4110 in an overdriven condition.

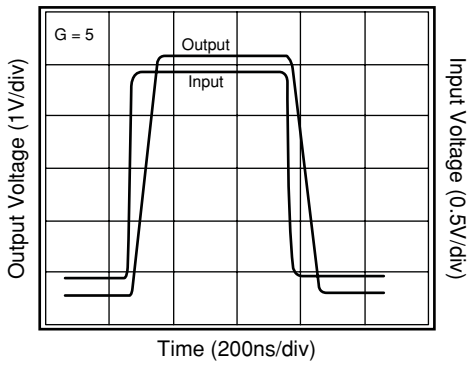


Figure 4: Overdrive Recovery

Driving Capacitive Loads

The Frequency Response vs. C_L plot on page 4, illustrates the response of the KM4110 and KM4120. A small series resistance (R_s) at the output of the amplifier, illustrated in Figure 5, will improve stability and settling performance. R_s values in the Frequency Response vs. C_L plot were chosen to achieve maximum bandwidth with less than 1dB of peaking. For maximum flatness, use a larger R_s.

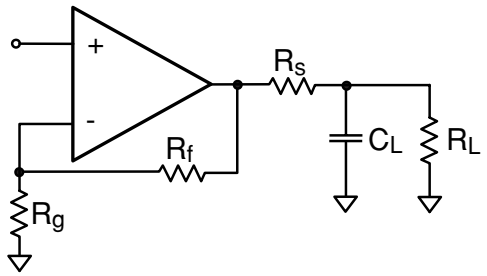


Figure 5: Typical Topology for driving a capacitive load

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. Fairchild has evaluation boards to use as a guide for high frequency layout and to aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8μF and 0.01μF ceramic capacitors
- Place the 6.8μF capacitor within 0.75 inches of the power pin
- Place the 0.01μF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

When evaluating only one channel, complete the following on the unused channel

1. Ground the non-inverting input
2. Short the output to the inverting input

Refer to the evaluation board layouts shown in Figure 7 for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of this device:

Eval Board	Description	Products
KEB006	Dual Channel, Dual Supply 8 lead SOIC	KM4210IC8
KEB010	Dual Channel, Dual Supply 8 lead MSOP	KM4210IM8

Evaluation board schematics and layouts are shown in Figure 6 and Figure 7.

The KEB006 evaluation board is built for dual supply operation. Follow these steps to use the board in a single supply application:

1. Short $-V_s$ to ground
2. Use C3 and C4, if the $-V_s$ pin of the KM4210 is not directly connected to the ground plane.

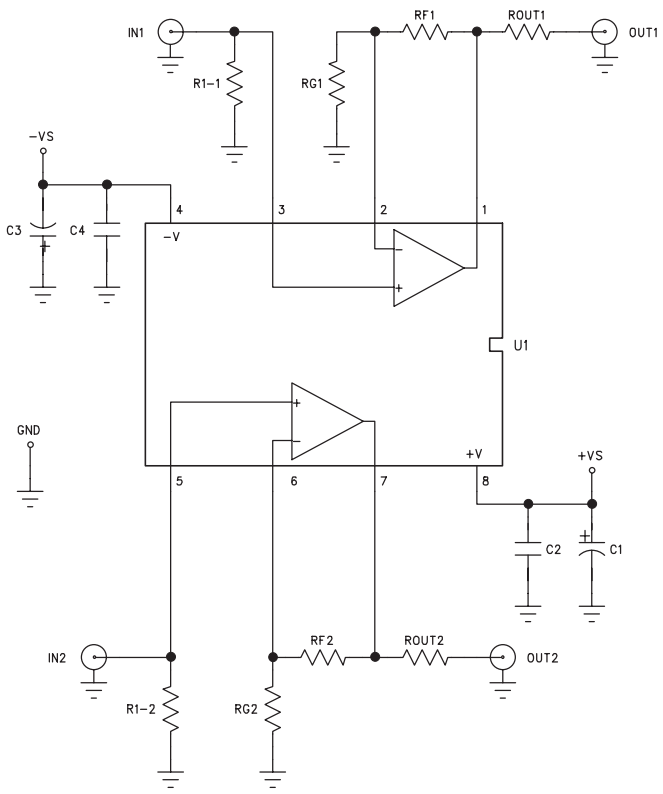


Figure 6: Evaluation Board Schematic

KM4210 Evaluation Board Layout

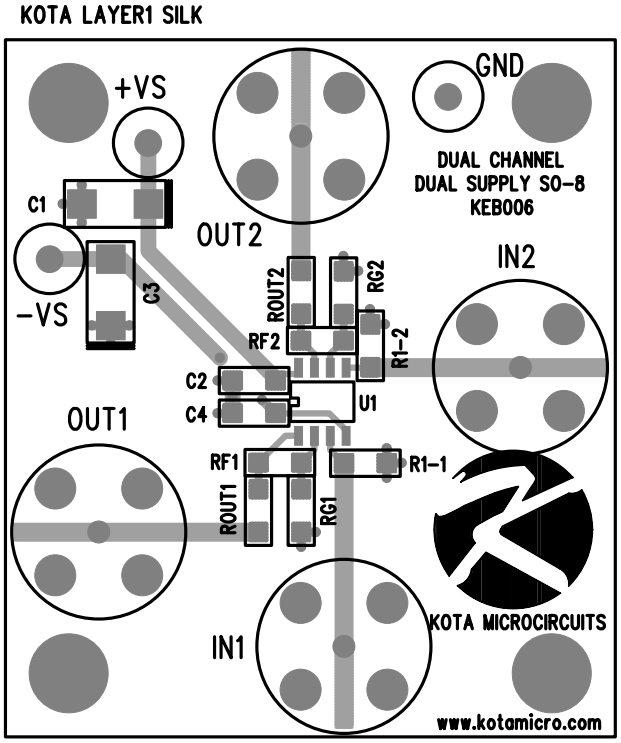


Figure 7a: KEB006 (top side)

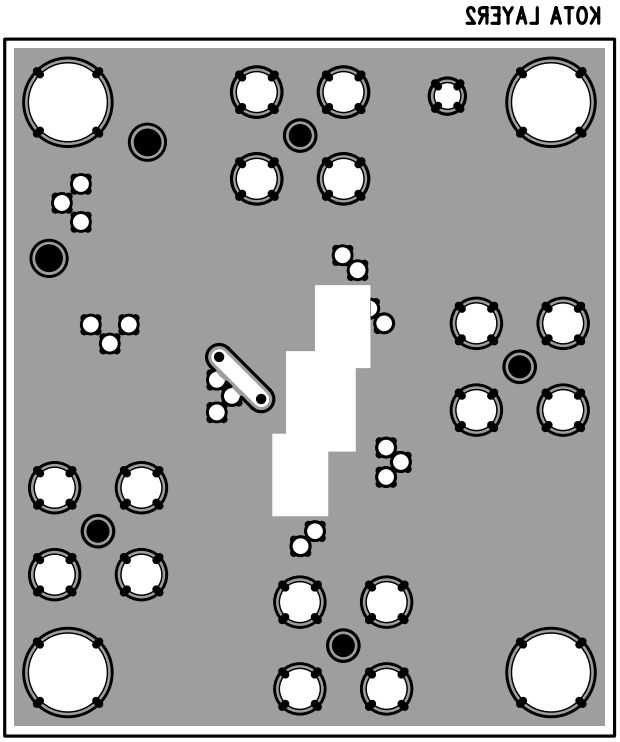


Figure 7b: KEB006 (bottom side)

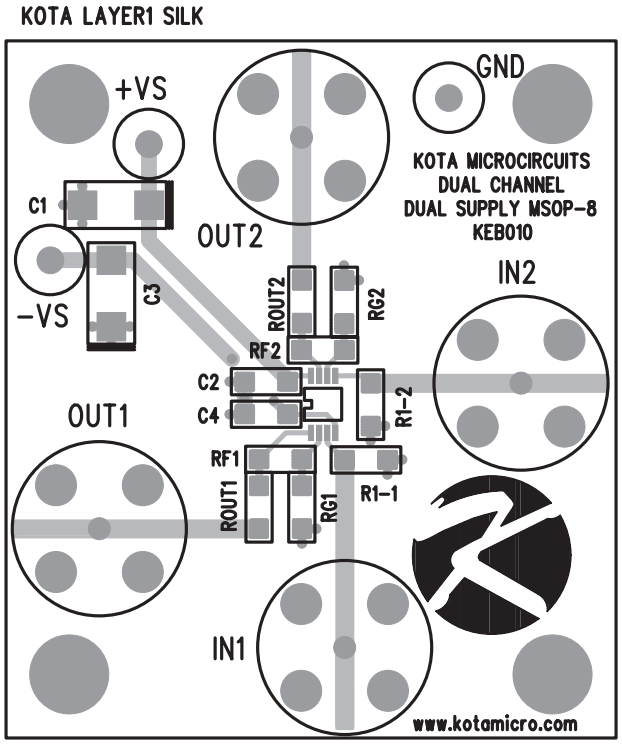


Figure 7c: KEB010 (top side)

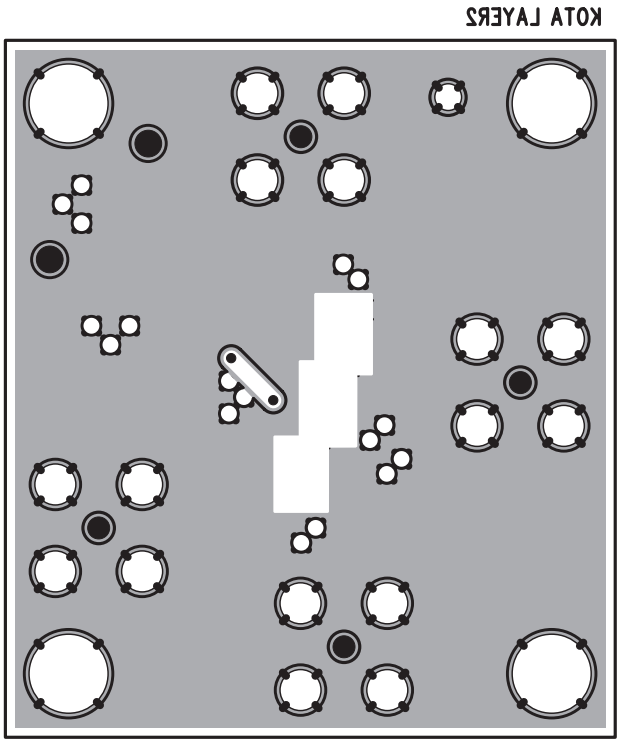
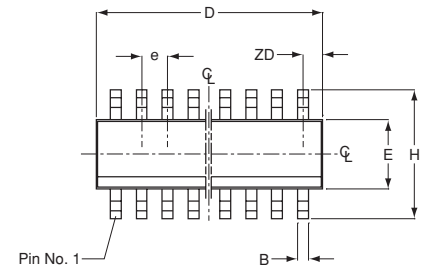
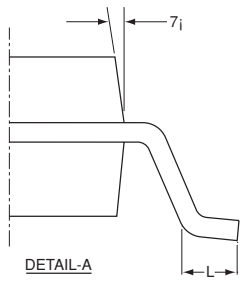


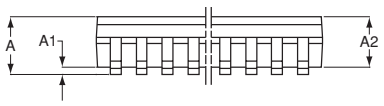
Figure 7d: KEB010 (bottom side)

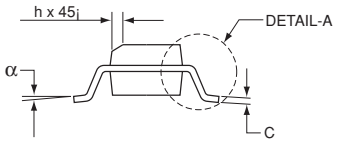
KM4210 Package Dimensions

SOIC







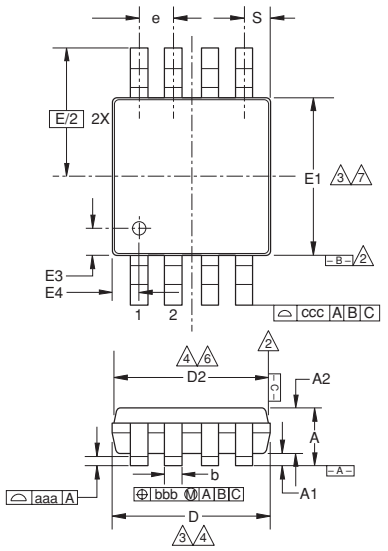


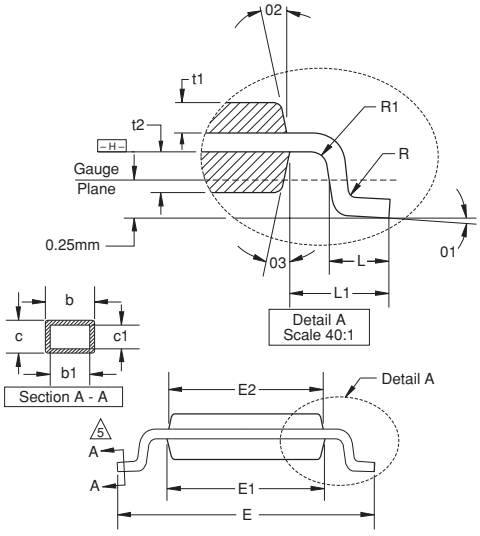
SOIC-8		
SYMBOL	MIN	MAX
A1	0.10	0.25
B	0.36	0.46
C	0.19	0.25
D	4.80	4.98
E	3.81	3.99
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.41	1.27
A	1.52	1.72
	0°	8°
ZD	0.53 ref	
A2	1.37	1.57

NOTE:

1. All dimensions are in millimeters.
2. Lead coplanarity should be 0 to 0.10mm (.004") max.
3. Package surface finishing:
   (2.1) Top: matte (charmilles #18~30).
   (2.2) All sides: matte (charmilles #18~30).
   (2.3) Bottom: smooth or matte (charmilles #18~30).
4. All dimensions excluding mold flashes and end flash from the package body shall not exceed o.152mm (.006) per side(d).

MSOP





MSOP-8		
SYMBOL	MIN	MAX
A	1.10	–
A1	0.10	±0.05
A2	0.86	±0.08
D	3.00	±0.10
D2	2.95	±0.10
E	4.90	±0.15
E1	3.00	±0.10
E2	2.95	±0.10
E3	0.51	±0.13
E4	0.51	±0.13
R	0.15	+0.15/-0.06
R1	0.15	+0.15/-0.06
t1	0.31	±0.08
t2	0.41	±0.08
b	0.33	+0.07/-0.08
b1	0.30	±0.05
c	0.18	±0.05
c1	0.15	+0.03/-0.02
01	3.0°	±3.0°
02	12.0°	±3.0°
03	12.0°	±3.0°
L	0.55	±0.15
L1	0.95 BSC	–
aaa	0.10	–
bbb	0.08	–
ccc	0.25	–
e	0.65 BSC	–
S	0.525 BSC	–

NOTE:

1 All dimensions are in millimeters (angle in degrees), unless otherwise specified.

2 Datums –B– and –C– to be determined at datum plane –H–.

3 Dimensions "D" and "E1" are to be determined at datum –H–.

4 Dimensions "D2" and "E2" are for top package and dimensions "D" and "E1" are for bottom package.

5 Cross sections A – A to be determined at 0.13 to 0.25mm from the leadtip.

6 Dimension "D" and "D2" does not include mold flash, protrusion or gate burrs.

7 Dimension "E1" and "E2" does not include interlead flash or protrusion.

Ordering Information

Model	Part Number	Package	Container	Pack Qty
KM4210	KM4210IC8	SOIC-8	Rail	95
KM4210	KM4210IC8TR3	SOIC-8	Reel	2500
KM4210	KM4210IM8	MSOP-8	Rail	50
KM4210	KM4210IM8TR3	MSOP-8	Reel	4000

Temperature range for all parts: -40°C to +85°C